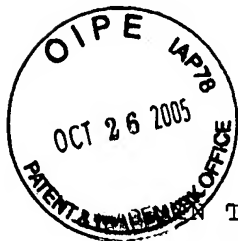


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BY TELEFAX 703-746-9195

DOCKET NO.: 4878

THE UNITED STATES PATENT AND TRADEMARK OFFICE  
IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Seiji NAKAHATA et al.

| ART UNIT: 2812

SERIAL NO.: 10/535,741

| CONF. NO.: 9438

FILED: May 18, 2005

FOR: METHOD OF PROCESSING SURFACE OF NITRIDE SEMICONDUCTOR  
CRYSTAL AND NITRIDE SEMICONDUCTOR CRYSTAL OBTAINED WITH THE  
METHOD

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October 26, 2005

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Respectfully submitted,  
Seiji NAKAHATA et al.-Applicant

WFF:ks/4878

Enclosure:  
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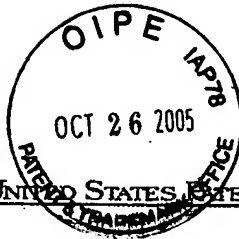
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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/535,741	05/18/2005	2812	900	4878/PCT	1	12	3

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\*OC000000017046154\*

CONFIRMATION NO. 9438

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Assignment for Published Patent Application  
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Yusuke MORI, Katano-shi, JAPAN  
Power of Attorney: The patent practitioners associated with Customer Number 21553.

## Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP04/08090 06/03/2004

## Foreign Applications

JAPAN 2003-170584 06/16/2003

Projected Publication Date: 12/29/2005

Non-Publication Request: No

Early Publication Request: No

Title

see next page

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X  
Method of surface of  
Method for processing nitride semiconductor crystal surface and nitride semiconductor crystal  
obtained by such method  
with the  
Preliminary Class

438

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